

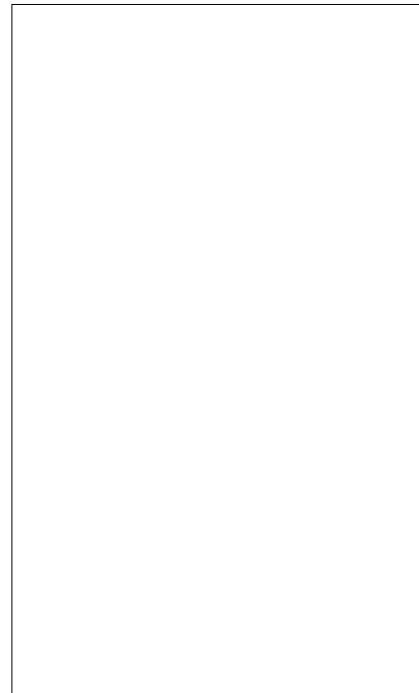


JCT816K 16A SCR

Rev. A. 1.0

**DESCRIPTION:**

With high ability to withstand the shock loading of large current, JCT816K of silicon controlled rectifiers provides high  $dV/dt$  rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-252 is RoHS compliant.



**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT}$	"15	mA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-1	

Average gate power dissipation ( $f_{sw}=125$ )	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	20	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off state; FIG.8)	$V_{pp}$	0.5	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25$  unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12V$ $R_L=33$	-	-	15	mA
$V_{GT}$		-	-	1	V

JCT816K

 JieJie Microelectronics Co., Ltd.

ORDERING INFORMATION

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FIG.1 Maximum power dissipation versus RMS on-state current

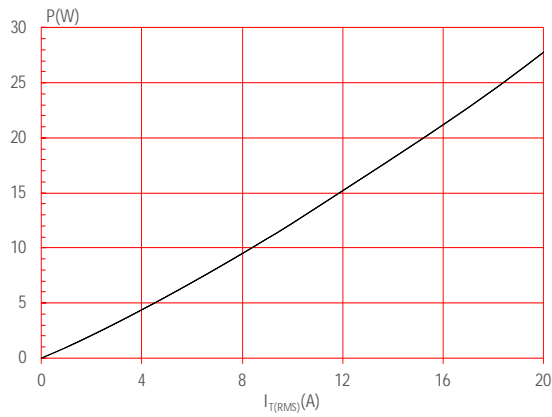


FIG.2: RMS on-state current versus case temperature

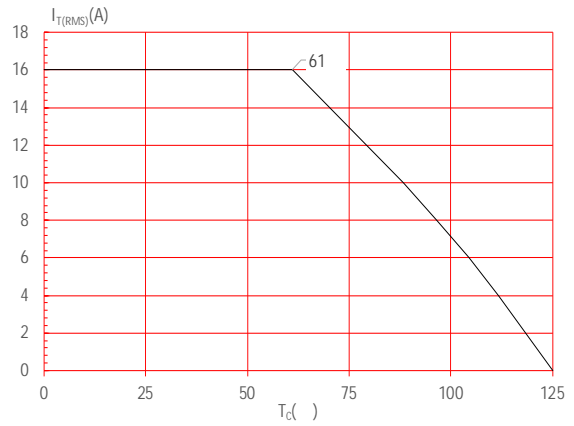


FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4,copper

WKL FNQHVV P IXOO F\FOH

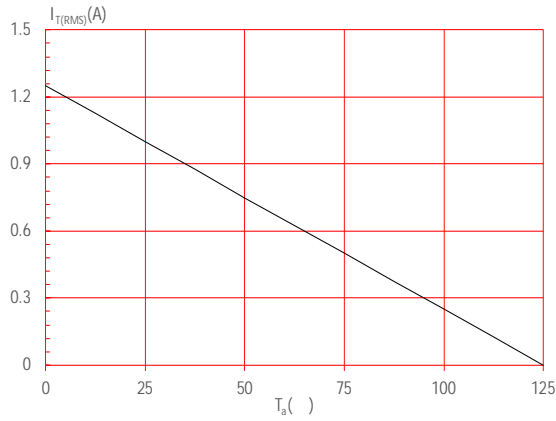


FIG.4: Surge peak onstate current versus number of cycles

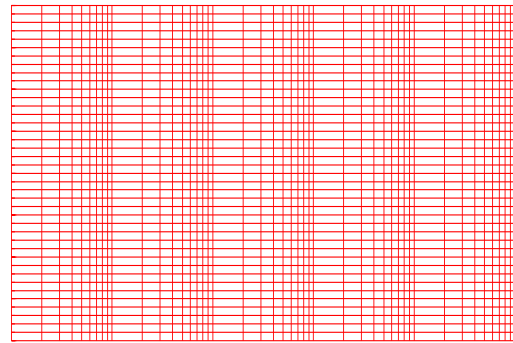


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

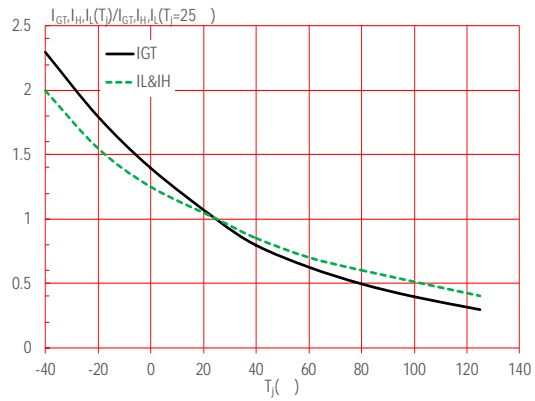
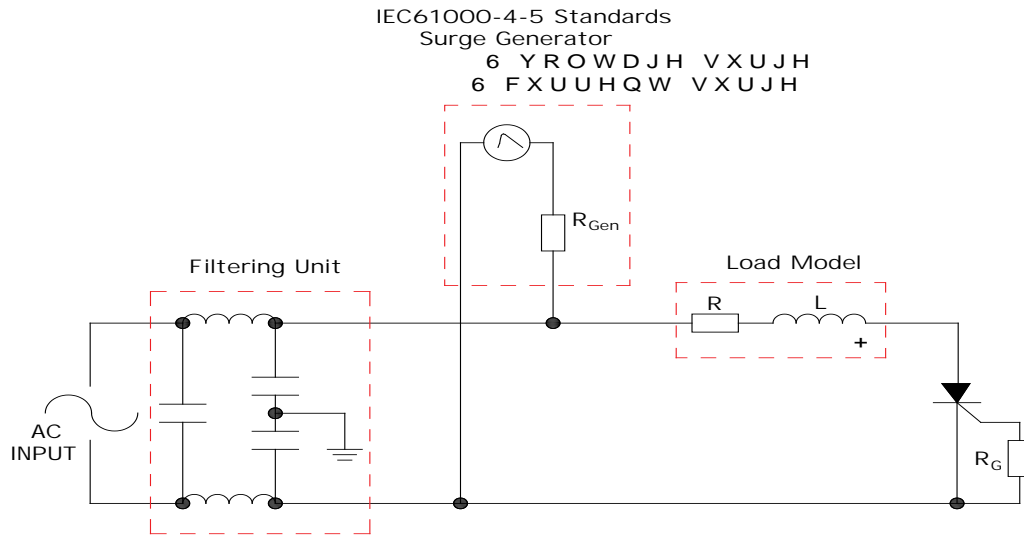
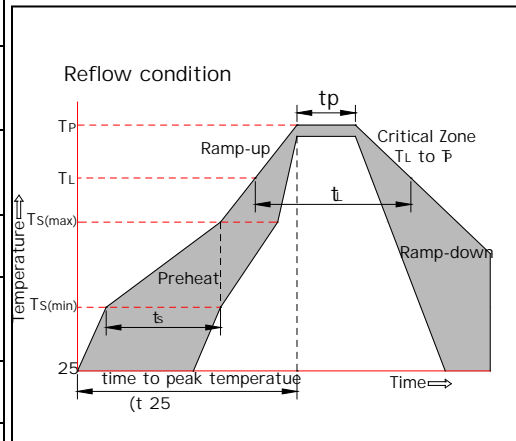


FIG.8 Test circuit for inductive and resistive loads to IEC61000-4-5 standards.



**SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{S(min)}$ )	+150
	-Temperature Max( $T_{S(max)}$ )	+200
	-Time (Min to Max) ( $t_s$ )	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3 /sec. Max
$T_{S(max)}$ to $T_L$ -Ramp-up Rate		3 /sec. Max
Reflow	-Temperature( $T$ ) (Liquidus)	+217
	-Temperature( $t$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0.5)
Time within 5 of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6 /sec. Max
Time 25 to Peak Temp ( $t_{25}$ )		8 min. Max
Do not exceed		+260



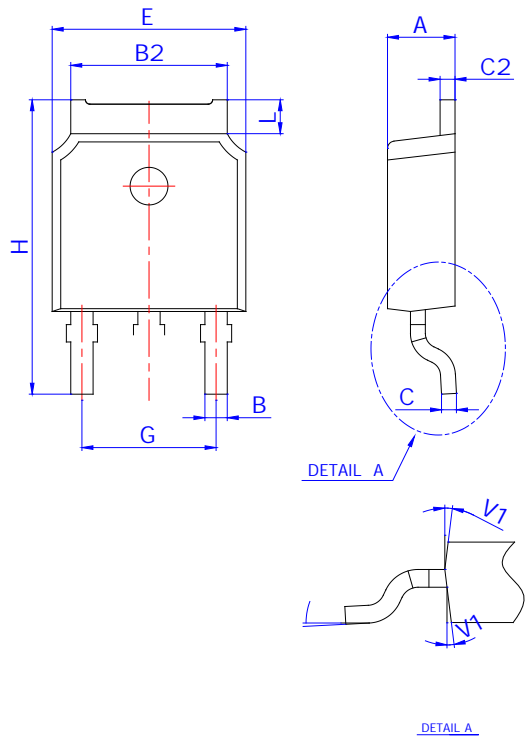
## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT 816K	800	15	TO-252	80	Tube
JCT816K-TR				2,500	Tape & Reel

## Document Revision History

Date	Revision	Changes
Apr.13, 2023	A.1.0	Last update

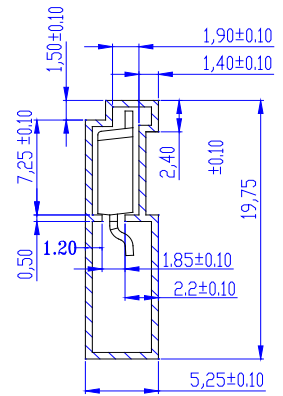
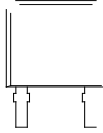
PACKAGE MECHANICAL DATA




Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.15	0		0.006
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1						
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°



DELIVERY MODE



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